

FEATURES

- Rx mixer with integrated fractional-N PLL
- RF input frequency range: 1100 MHz to 3200 MHz
- Internal LO frequency range: 2100 MHz to 2600 MHz
- Input P1dB: 14.6 dBm
- Input IP3: 27 dBm
- Input IP3 optimization via external pin
- SSB noise figure
 - IP3SET pin open: 14.2 dB
 - IP3SET pin at 3.3 V: 15.2 dB
- Voltage conversion gain: 6.9 dB
- Matched 200 Ω IF output impedance
- IF 3 dB bandwidth: 500 MHz
- Programmable via 3-wire SPI interface
- 40-lead, 6 mm × 6 mm LFCSP

APPLICATIONS

Cellular base stations

GENERAL DESCRIPTION

The ADRF6603 is a high dynamic range active mixer with integrated fractional-N phase-locked loop (PLL) and voltage-controlled oscillator (VCO) for internal mixer LO generation.

Along with the [ADRF6602](#), the ADRF6603 forms a family of integrated PLL/mixers that cover the frequency range of 2100 MHz to 2600 MHz.

Table 1.

Part No.	Internal LO Range	±3 dB RF _{IN} Balun Range	±1 dB RF _{IN} Balun Range
ADRF6602	1550 MHz	1000 MHz	1350 MHz
	2150 MHz	3100 MHz	2750 MHz
ADRF6603	2100 MHz	1100 MHz	1450 MHz
	2600 MHz	3200 MHz	2850 MHz

The PLL reference input can support input frequencies from 12 MHz to 160 MHz. The PFD output controls a charge pump whose output drives an off-chip loop filter.

The loop filter output is then applied to an integrated VCO. The VCO output at $2 \times f_{LO}$ is applied to an LO divider, as well as to a programmable PLL divider. The programmable PLL divider is controlled by a sigma-delta modulator (SDM). The modulus of the SDM can be programmed from 1 to 2047.

The active mixer converts the single-ended 50 Ω RF input to a 200 Ω differential IF output. The IF output can operate up to 500 MHz.

The ADRF6603 is fabricated using an advanced silicon-germanium BiCMOS process. It is available in a 40-lead, RoHS-compliant, 6 mm × 6 mm LFCSP with an exposed paddle. Performance is specified over the -40°C to $+85^{\circ}\text{C}$ temperature range.

FUNCTIONAL BLOCK DIAGRAM

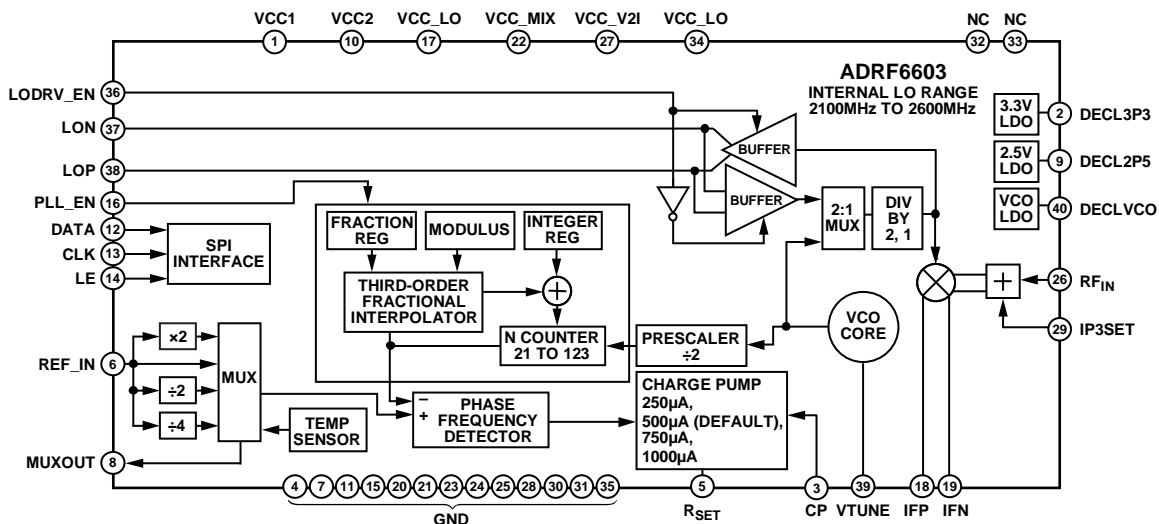


Figure 1.

Rev. 0

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REVISION HISTORY

3/10—Revision 0: Initial Version

SPECIFICATIONS

RF SPECIFICATIONS

$V_S = 5\text{ V}$; ambient temperature (T_A) = 25°C ; $f_{\text{REF}} = 38.4\text{ MHz}$; $f_{\text{PFD}} = 38.4\text{ MHz}$; high-side LO injection; $f_{\text{IF}} = 140\text{ MHz}$; IIP3 optimized using capacitor DAC (0x1) and IP3SET (3.3 V), unless otherwise noted.

Table 2.

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
INTERNAL LO FREQUENCY RANGE		2100		2600	MHz
RF INPUT FREQUENCY RANGE	$\pm 3\text{ dB}$ RF input range	1100		3200	MHz
RF INPUT AT 2140 MHz					
Input Return Loss	Relative to $50\ \Omega$ (can be improved with external match)		-27		dB
Input P1dB			14.6		dBm
Second-Order Intercept (IIP2)	-5 dBm each tone (10 MHz spacing between tones)		56		dBm
Third-Order Intercept (IIP3)	-5 dBm each tone (10 MHz spacing between tones)		28		dBm
Single-Side Band Noise Figure	IP3SET = 3.3 V		15.2		dB
	IP3SET = open		14.5		dB
LO to IF Leakage	At $1\times$ LO frequency, $50\ \Omega$ termination at the RF port		-42		dBm
RF INPUT AT 2400 MHz					
Input Return Loss	Relative to $50\ \Omega$ (can be improved with external match)		-16		dB
Input P1dB			14.6		dBm
Second-Order Intercept (IIP2)	-5 dBm each tone (10 MHz spacing between tones)		55		dBm
Third-Order Intercept (IIP3)	-5 dBm each tone (10 MHz spacing between tones)		27.7		dBm
Single-Side Band Noise Figure	IP3SET = 3.3 V		15.3		dB
	IP3SET = open		14.2		dB
LO to IF Leakage	At $1\times$ LO frequency, $50\ \Omega$ termination at the RF port		-43		dBm
RF INPUT AT 2650 MHz	Low side Injection				
Input Return Loss	Relative to $50\ \Omega$ (can be improved with external match)		-11		dB
Input P1dB			14.6		dBm
Second-Order Intercept (IIP2)	-5 dBm each tone (10 MHz spacing between tones)		54		dBm
Third-Order Intercept (IIP3)	-5 dBm each tone (10 MHz spacing between tones)		28.0		dBm
Single-Side Band Noise Figure	IP3SET = 3.3 V		15.3		dB
	IP3SET = open		14.2		dB
LO to IF Leakage	At $1\times$ LO frequency, $50\ \Omega$ termination at the RF port		-42.5		dBm
IF OUTPUT					
Voltage Conversion Gain	Differential $200\ \Omega$ load		6.9		dB
IF Bandwidth	Small-signal 3 dB bandwidth		500		MHz
Output Common-Mode Voltage	External pull-up balun or inductors required		5		V
Gain Flatness	Over frequency range, any 5 MHz/50 MHz		0.2/1.0		dB
Gain Variation	Over full temperature range		1.0		dB
Output Swing	Differential $200\ \Omega$ load		2		V p-p
Output Return Loss	Relative to $200\ \Omega$		-14		dB
LO INPUT/OUTPUT (LOP, LON)	Externally applied $1\times$ LO input, internal PLL disabled				
Frequency Range		250		6000	MHz
Output Level (LO as Output)	$1\times$ LO into a $50\ \Omega$ load, LO output buffer enabled		-7		dBm
Input Level (LO as Input)			± 6		dBm
Input Impedance			50		Ω

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SYNTHESIZER/PLL SPECIFICATIONS

$V_S = 5\text{ V}$; ambient temperature (T_A) = 25°C; $f_{REF} = 153.6\text{ MHz}$; $f_{PFD} = 38.4\text{ MHz}$; high-side LO injection; $f_{IF} = 140\text{ MHz}$; IIP3 optimized using capacitor DAC (0x1) and IP3SET (3.3 V), unless otherwise noted.

Table 3.

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
SYNTHESIZER SPECIFICATIONS	Synthesizer specifications referenced to 1× LO				
Frequency Range	Internally generated LO	2100		2600	MHz
Figure of Merit	$P_{REF_IN} = 0\text{ dBm}$		-222		dBc/Hz
Reference Spurs	$f_{REF} = 153.6\text{ MHz}$				
	$f_{REF}/4$		-107		dBc
	$f_{REF}/2$		-107		dBc
	f_{REF}		-86		dBc
	$> f_{REF}$		-83		dBc
PHASE NOISE	$f_{LO} = 2100\text{ MHz to }2600\text{ MHz}$, $f_{PFD} = 38.4\text{ MHz}$				
	1 kHz to 10 kHz offset		-90		dBc/Hz
	100 kHz offset		-99.5		dBc/Hz
	500 kHz offset		-120		dBc/Hz
	1 MHz offset		-128		dBc/Hz
	5 MHz offset		-142		dBc/Hz
	10 MHz offset		-148		dBc/Hz
	20 MHz offset		-149		dBc/Hz
Integrated Phase Noise	1 kHz to 40 MHz integration bandwidth		0.4		°rms
PFD Frequency		20		40	MHz
REFERENCE CHARACTERISTICS	REF_IN, MUXOUT pins				
REF_IN Input Frequency		12		160	MHz
REF_IN Input Capacitance			4		pF
MUXOUT Output Level	V_{OL} (lock detect output selected)			0.25	V
	V_{OH} (lock detect output selected)	2.7			V
MUXOUT Duty Cycle			50		%
CHARGE PUMP					
Pump Current	Programmable to 250 μA , 500 μA , 750 μA , 1 mA		500		μA
Output Compliance Range		1		2.8	V

LOGIC INPUT AND POWER SPECIFICATIONS

$V_S = 5\text{ V}$; ambient temperature (T_A) = 25°C ; $f_{REF} = 38.4\text{ MHz}$; $f_{PFD} = 38.4\text{ MHz}$; high-side LO injection; $f_{IF} = 140\text{ MHz}$; IIP3 optimized using capacitor DAC (0x1) and IP3SET (3.3 V), unless otherwise noted.

Table 4.

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
LOGIC INPUTS	CLK, DATA, LE				
Input High Voltage, V_{INH}		1.4		3.3	V
Input Low Voltage, V_{INL}		0		0.7	V
Input Current, I_{INH}/I_{INL}			0.1		μA
Input Capacitance, C_{IN}			5		pF
POWER SUPPLIES	VCC1, VCC2, VCC_LO, VCC_MIX, and VCC_V2I pins				
Voltage Range		4.75	5	5.25	V
Supply Current	PLL only		98		mA
	External LO mode (internal PLL disabled, IP3SET pin = 3.3 V)		163		mA
	Internal LO mode (internal PLL enabled, IP3SET pin = 3.3 V)		261		mA
	Power-down mode		30		mA

TIMING CHARACTERISTICS

$VCC2 = 5\text{ V} \pm 5\%$.

Table 5.

Parameter	Limit	Unit	Description
t_1	20	ns min	LE setup time
t_2	10	ns min	DATA to CLK setup time
t_3	10	ns min	DATA to CLK hold time
t_4	25	ns min	CLK high duration
t_5	25	ns min	CLK low duration
t_6	10	ns min	CLK to LE setup time
t_7	20	ns min	LE pulse width

Timing Diagram

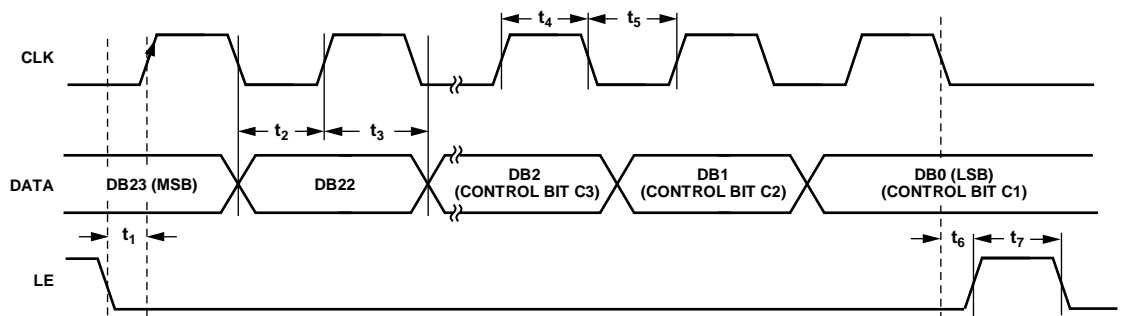


Figure 2. Timing Diagram

ABSOLUTE MAXIMUM RATINGS

Table 6.

Parameter	Rating
Supply Voltage, VCC1, VCC2, VCC_LO, VCC_MIX, VCC_V2I	-0.5 V to +5.5 V
Digital I/O, CLK, DATA, LE	-0.3 V to +3.6 V
IFP, IFN	-0.3 V to VCC + 0.3 V
RF _{IN}	18 dBm
θ _{JA} (Exposed Paddle Soldered Down)	35°C/W
Maximum Junction Temperature	150°C
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	-65°C to +150°C

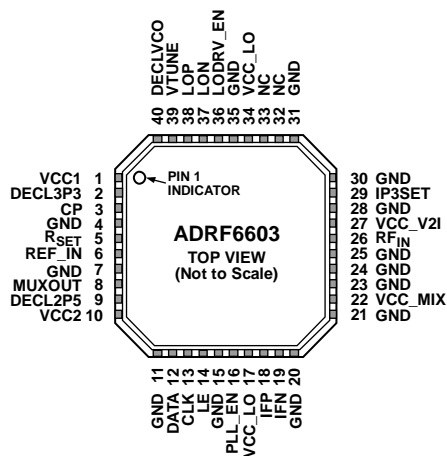
Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



NOTES
 1. NC = NO CONNECT.
 2. THE EXPOSED PADDLE SHOULD BE SOLDERED TO A LOW IMPEDANCE GROUND PLANE.

Figure 3. Pin Configuration

Table 7. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	VCC1	Power Supply for the 3.3 V LDO. Power supply voltage range is 4.75 V to 5.25 V. Each power supply pin should be decoupled with a 100 pF capacitor and a 0.1 μF capacitor located close to the pin.
2	DECL3P3	Decoupling Node for 3.3 V LDO. Connect a 0.1 μF capacitor between this pin and ground.
3	CP	Charge Pump Output Pin. Connect to VTUNE through the loop filter.
4, 7, 11, 15, 20, 21, 23, 24, 25, 28, 30, 31, 35	GND	Ground. Connect these pins to a low impedance ground plane.
5	R _{SET}	Charge Pump Current. The nominal charge pump current can be set to 250 μA, 500 μA, 750 μA, or 1 mA using Bit DB11 and Bit DB10 in Register 4 and by setting Bit DB18 to 0 (internal reference current). In this mode, no external R _{SET} is required. If Bit DB18 is set to 1, the four nominal charge pump currents (I _{NOMINAL}) can be externally adjusted according to the following equation: $R_{SET} = \left(\frac{217.4 \times I_{CP}}{I_{NOMINAL}} \right) - 37.8 \Omega$
6	REF_IN	Reference Input. Nominal input level is 1 V p-p. Input range is 12 MHz to 160 MHz.
8	MUXOUT	Multiplexer Output. This output can be programmed to provide the reference output signal or the lock detect signal. The output is selected by programming the appropriate register.
9	DECL2P5	Decoupling Node for 2.5 V LDO. Connect a 0.1 μF capacitor between this pin and ground.
10	VCC2	Power Supply for the 2.5 V LDO. Power supply voltage range is 4.75 V to 5.25 V. Each power supply pin should be decoupled with a 100 pF capacitor and a 0.1 μF capacitor located close to the pin.
12	DATA	Serial Data Input. The serial data input is loaded MSB first; the three LSBs are the control bits.
13	CLK	Serial Clock Input. The serial clock input is used to clock in the serial data to the registers. The data is latched into the 24-bit shift register on the CLK rising edge. Maximum clock frequency is 20 MHz.
14	LE	Load Enable. When the LE input pin goes high, the data stored in the shift registers is loaded into one of the eight registers. The relevant latch is selected by the three control bits of the 24-bit word.
16	PLL_EN	PLL Enable. Switch between internal PLL and external LO input. When this pin is logic high, the mixer LO is automatically switched to the internal PLL and the internal PLL is powered up. When this pin is logic low, the internal PLL is powered down and the external LO input is routed to the mixer LO inputs. The SPI can also be used to switch modes.
17, 34	VCC_LO	Power Supply. Power supply voltage range is 4.75 V to 5.25 V. Each power supply pin should be decoupled with a 100 pF capacitor and a 0.1 μF capacitor located close to the pin.
18, 19	IFP, IFN	Mixer IF Outputs. These outputs should be pulled to VCC with RF chokes.
22	VCC_MIX	Power Supply. Power supply voltage range is 4.75 V to 5.25 V. Each power supply pin should be decoupled with a 100 pF capacitor and a 0.1 μF capacitor located close to the pin.
26	RF _{IN}	RF Input (Single-Ended, 50 Ω).

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Pin No.	Mnemonic	Description
27	VCC_V2I	Power Supply. Power supply voltage range is 4.75 V to 5.25 V. Each power supply pin should be decoupled with a 100 pF capacitor and a 0.1 μ F capacitor located close to the pin.
29	IP3SET	Connect a resistor from this pin to a +5 V supply to adjust IIP3. Normally leave open.
32, 33	NC	No Connection.
36	LODRV_EN	LO Driver Enable. Together with Pin 16 (PLL_EN), this digital input pin determines whether the LOP and LON pins operate as inputs or outputs. LOP and LON become inputs if the PLL_EN pin is low or if the PLL_EN pin is set high with the PLEN bit (DB6 in Register 5) set to 0. LOP and LON become outputs if either the LODRV_EN pin or the LDRV bit (DB3 in Register 5) is set to 1 while the PLL_EN pin is set high. The external LO drive frequency must be $1\times$ LO. This pin should not be left floating.
37, 38	LON, LOP	Local Oscillator Input/Output. The internally generated $1\times$ LO is available on these pins. When internal LO generation is disabled, an external $1\times$ LO can be applied to these pins.
39	VTUNE	VCO Control Voltage Input. This pin is driven by the output of the loop filter. The nominal input voltage range on this pin is 1.5 V to 2.5 V.
40	DECLVCO	Decoupling Node for VCO LDO. Connect a 100 pF capacitor and a 10 μ F capacitor between this pin and ground.
EP	EPAD	Exposed Paddle. The exposed paddle should be soldered to a low impedance ground plane.

TYPICAL PERFORMANCE CHARACTERISTICS

CDAC = 0x1, IP3SET = 3.3 V, internally generated LO, $RF_{IN} = -10$ dBm, $f_{IF} = 140$ MHz, unless otherwise noted.

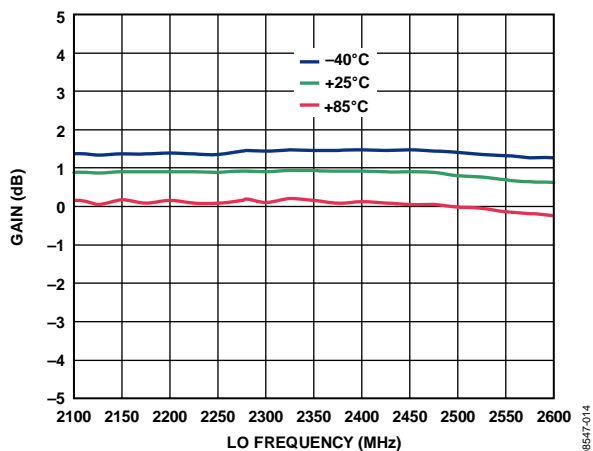


Figure 4. Gain vs. LO Frequency

08547-014

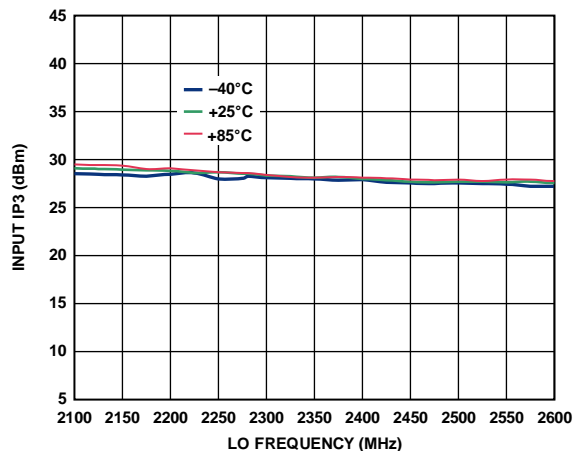


Figure 7. IIP3 vs. LO Frequency, $RF_{IN} = -5$ dBm

08547-017

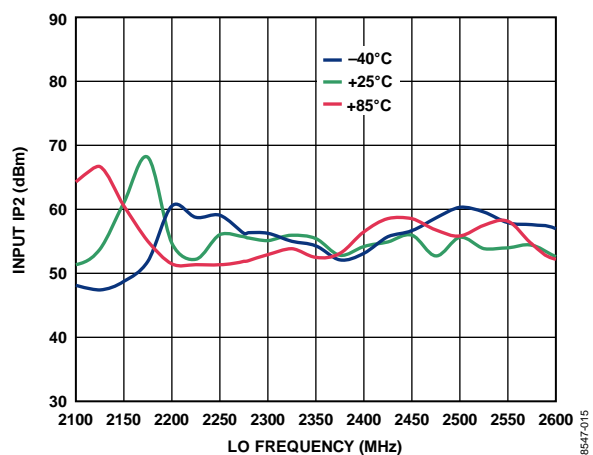


Figure 5. IIP2 vs. LO Frequency, $RF_{IN} = -5$ dBm

08547-015

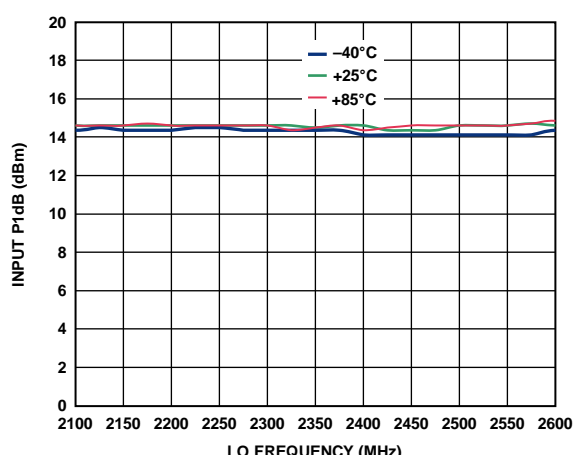


Figure 8. IP1dB vs. LO Frequency

08547-018

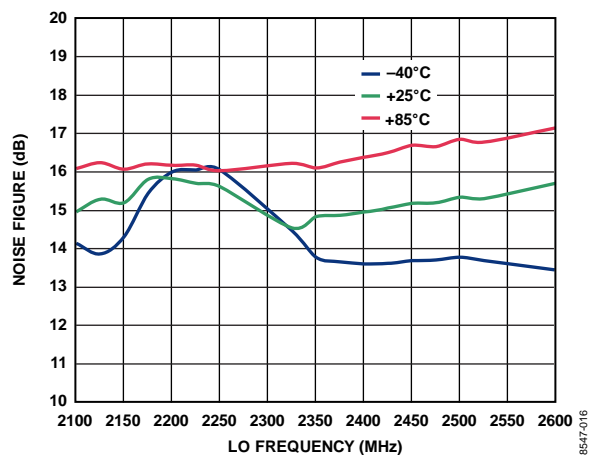


Figure 6. Noise Figure vs. LO Frequency

08547-016

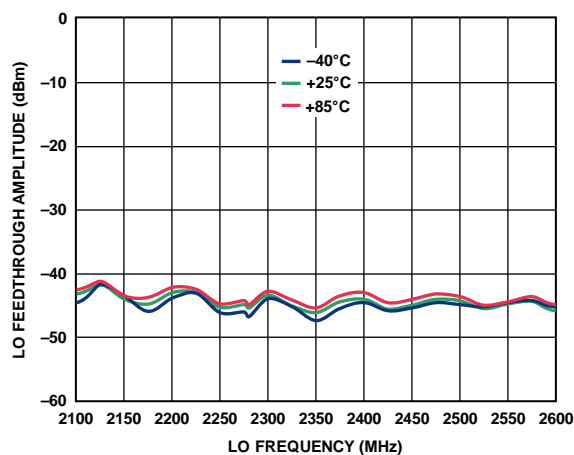


Figure 9. LO Feedthrough to IF vs. LO Frequency, LO Output Turned Off

08547-019

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Phase noise measurements made at IF output, unless otherwise noted.

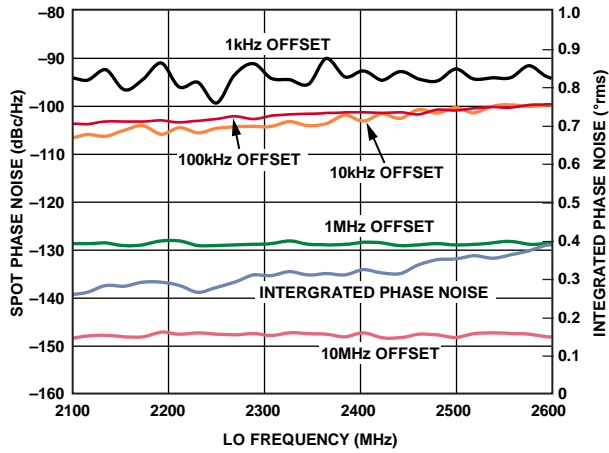


Figure 10. PLL Spot Phase Noise at Various Offsets and Integrated Phase Noise vs. LO Frequency

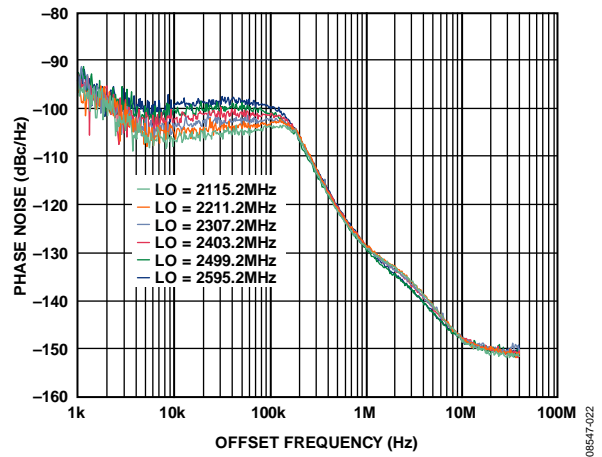


Figure 12. Phase Noise vs. Offset Frequency and LO Frequency (LO Frequency Varies from 2100 MHz to 2600 MHz)

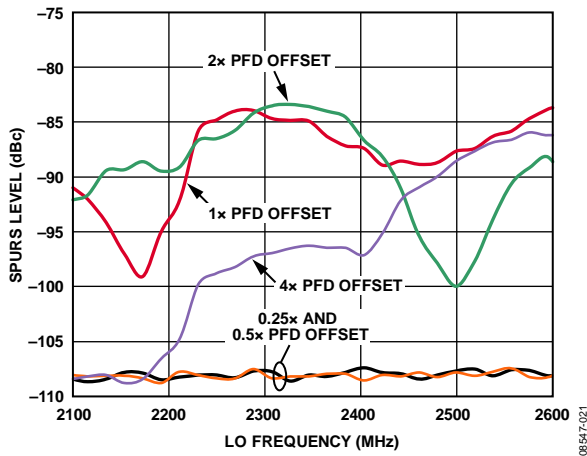


Figure 11. PLL Reference Spurs vs. LO Frequency

REGISTER STRUCTURE

This section provides the register maps for the ADRF6603. The three LSBs determine the register that is programmed.

REGISTER 0—INTEGER DIVIDE CONTROL (DEFAULT: 0x0001C0)

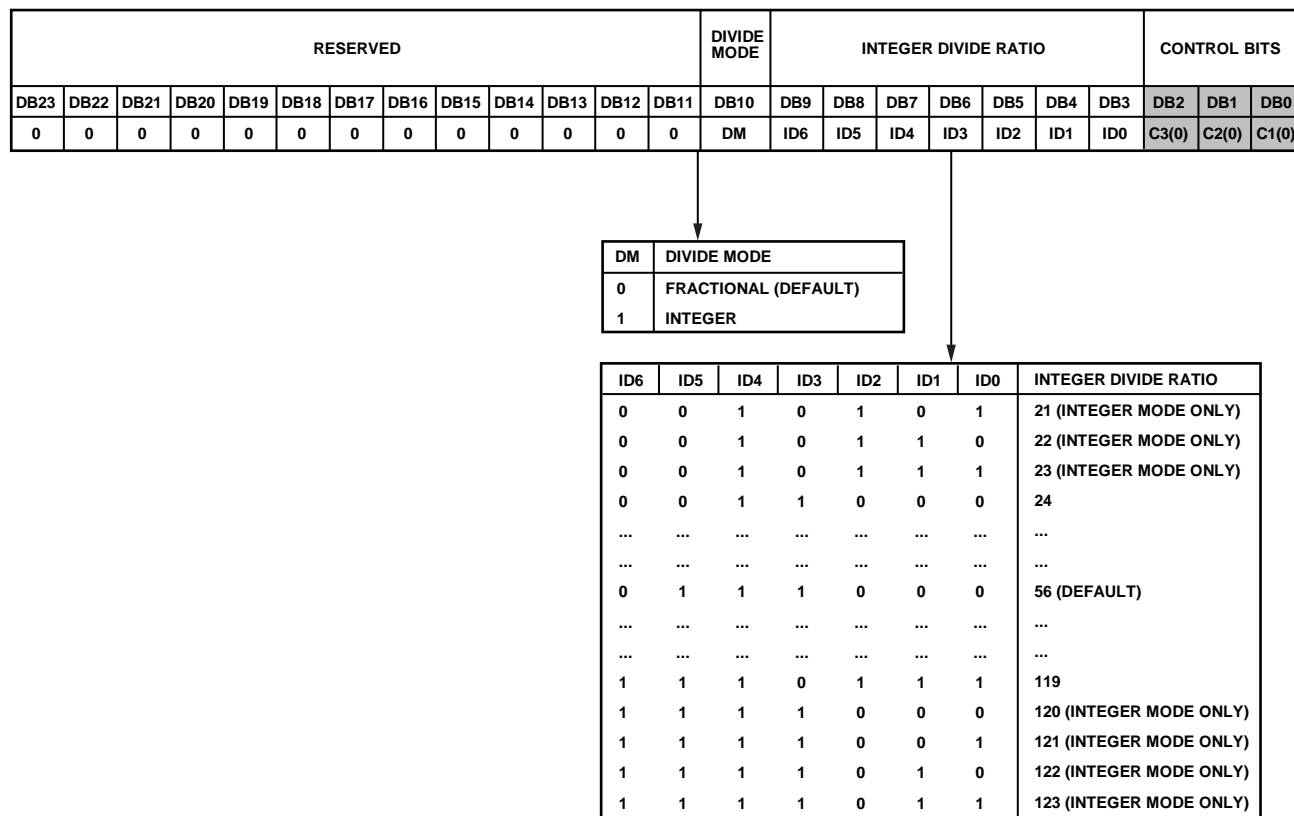


Figure 13. Register 0—Integer Divide Control Register Map

REGISTER 1—MODULUS DIVIDE CONTROL (DEFAULT: 0x003001)

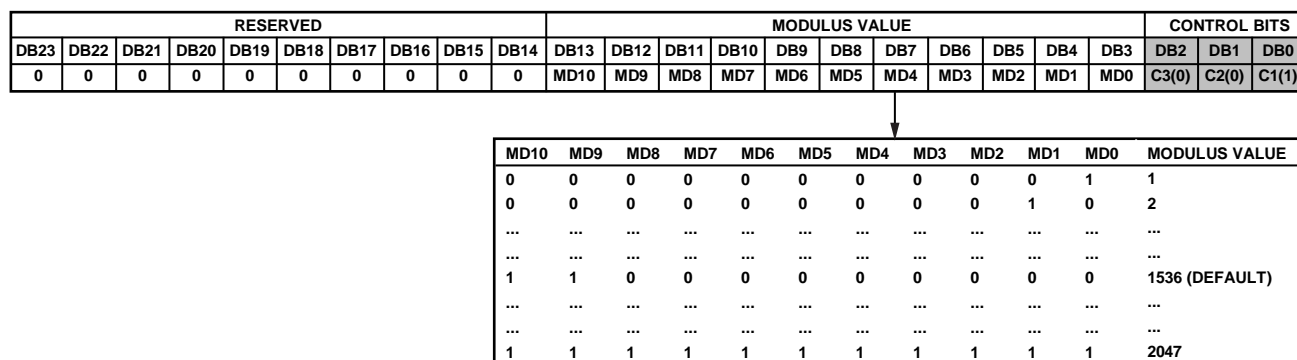


Figure 14. Register 1—Modulus Divide Control Register Map

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REGISTER 2—FRACTIONAL DIVIDE CONTROL (DEFAULT: 0x001802)

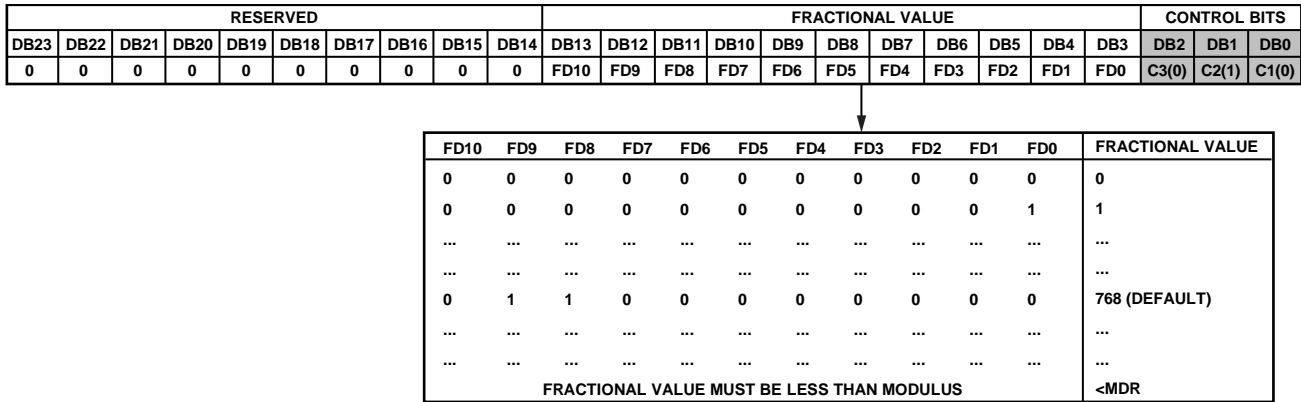


Figure 15. Register 2—Fractional Divide Control Register Map

08547-006

REGISTER 3—Σ-Δ MODULATOR DITHER CONTROL (DEFAULT: 0x10000B)

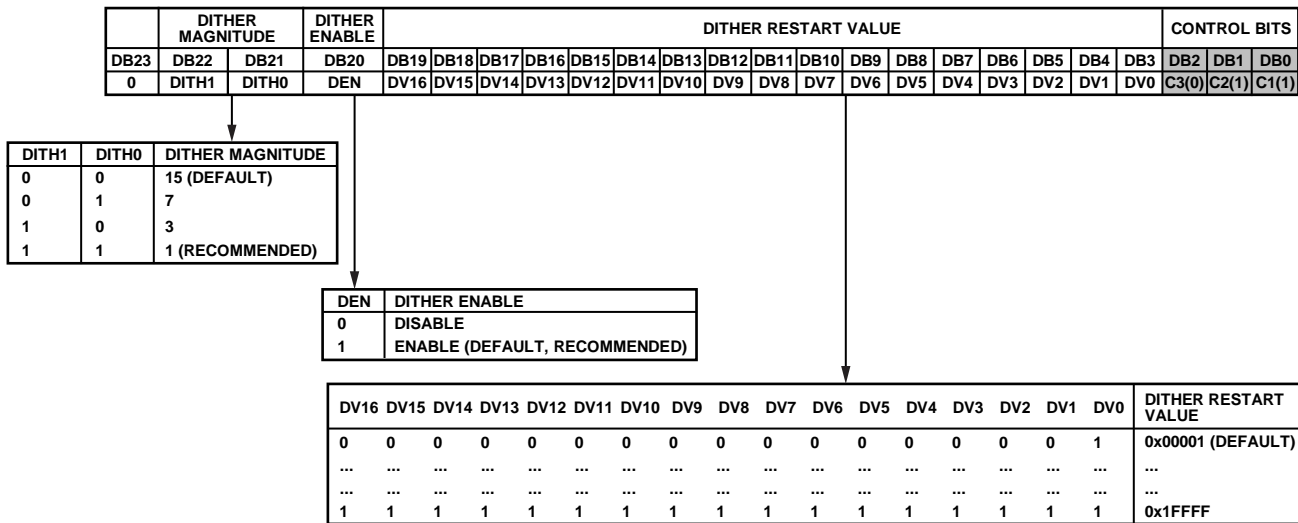


Figure 16. Register 3—Σ-Δ Modulator Dither Control Register Map

08547-007

REGISTER 4—PLL CHARGE PUMP, PFD, AND REFERENCE PATH CONTROL (DEFAULT: 0x0AA7E4)

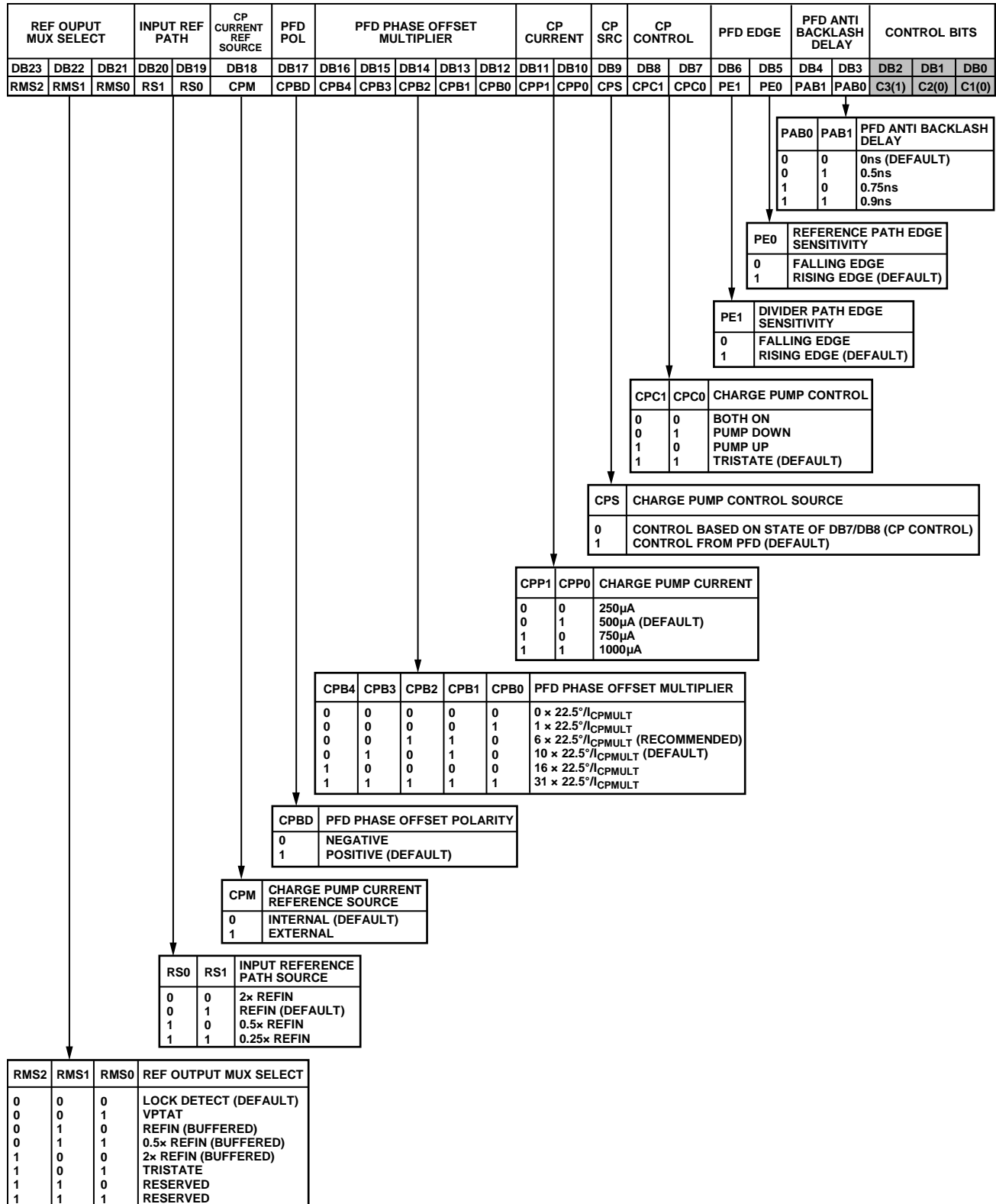


Figure 17. Register 4—PLL Charge Pump, PFD, and Reference Path Control Register Map

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REGISTER 5—PLL ENABLE AND LO PATH CONTROL (DEFAULT: 0x0000E5)

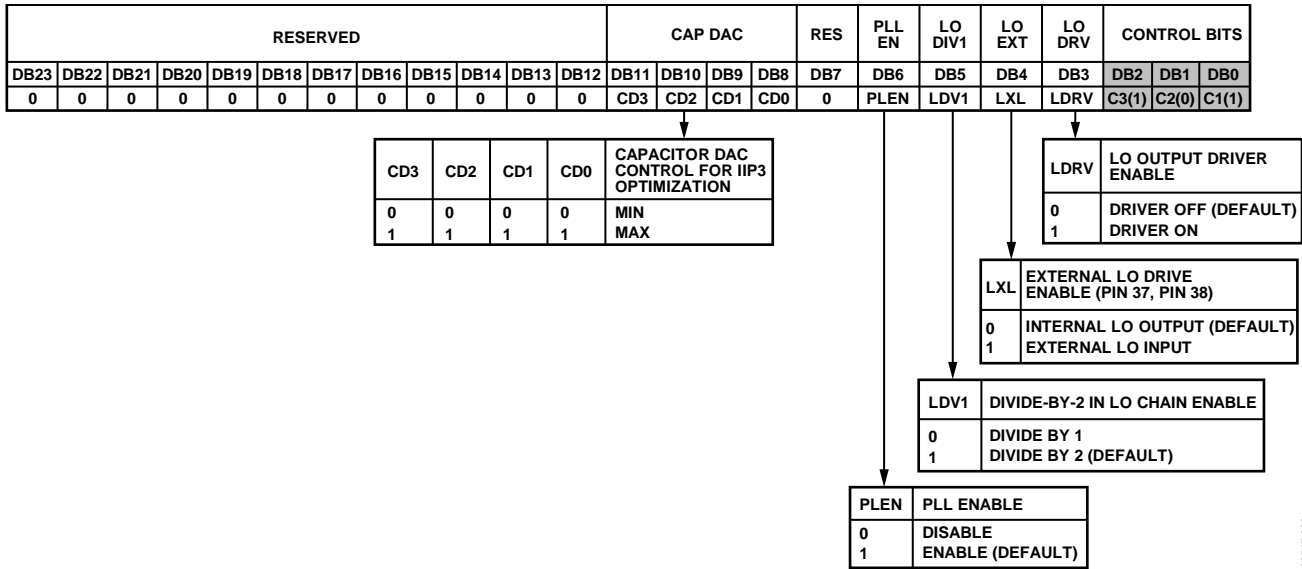


Figure 18. Register 5—PLL Enable and LO Path Control Register Map

REGISTER 6—VCO CONTROL AND VCO ENABLE (DEFAULT: 0x1E2106)

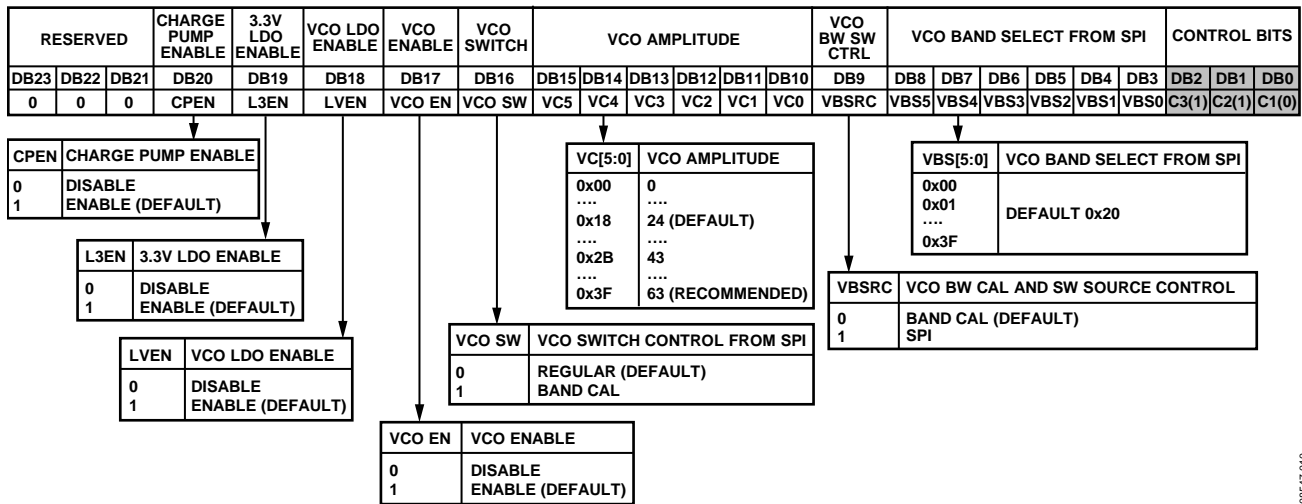


Figure 19. Register 6—VCO Control and VCO Enable Register Map

REGISTER 7—MIXER BIAS ENABLE AND EXTERNAL VCO ENABLE (DEFAULT: 0x000007)

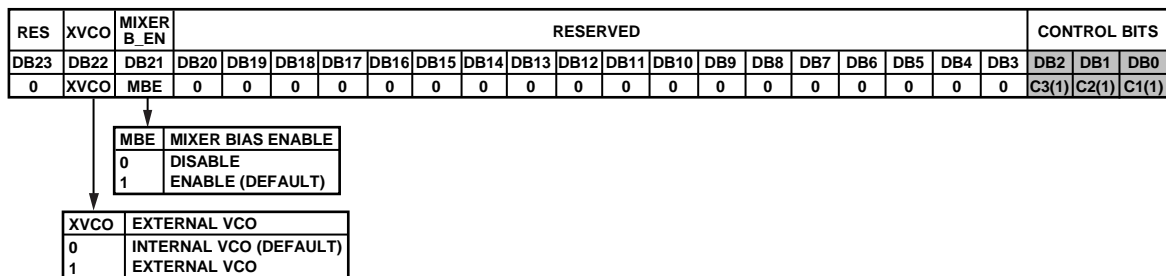


Figure 20. Register 7—Mixer Bias Enable and External VCO Enable Register Map

THEORY OF OPERATION

The ADRF6603 integrates a high performance downconverting mixer with a state-of-the-art fractional-N PLL. The PLL also integrates a low noise VCO. The SPI port allows the user to control the fractional-N PLL functions and the mixer optimization functions, as well as allowing for an externally applied LO or VCO.

The mixer core within the ADRF6603 is the next generation of an industry leading family of mixers from Analog Devices, Inc. The RF input is converted to a current and then mixed down to IF using high performance NPN transistors. The mixer output currents are transformed to a differential output. The high performance active mixer core results in an exceptional IIP3 and IP1dB, with a very low output noise floor for excellent dynamic range. Over the specified frequency range, the ADRF6603 typically provides an IF input P1dB of 14.6 dBm and an IIP3 of 27 dBm.

Improved performance at specific frequencies can be achieved with the use of the internal capacitor DAC (CDAC), which is programmable via the SPI port, and through the use of a resistor to a +5 V supply from the IP3SET pin (Pin 29). Adjustment of the capacitor DAC allows increments in phase shift at internal nodes in the ADRF6603, thus allowing cancellation of third-order distortion with no change in supply current. Connecting a resistor to a +5 V supply from the IP3SET pin increases the internal mixer core current, thereby improving overall IIP2 and IIP3, as well as IP1dB. Using the IP3SET pin for this purpose increases the overall supply current.

The fractional divide function of the PLL allows the frequency multiplication value from REF_IN to LO output to be a fractional value rather than be restricted to an integer value as in traditional PLLs. In operation, this multiplication value is $INT + (FRAC/MOD)$, where INT is the integer value, FRAC is the fractional value, and MOD is the modulus value, all programmable via the SPI port. In other fractional-N PLL designs, fractional multiplication is achieved by periodically changing the fractional value in a deterministic way. The disadvantage of this approach is often spurious components close to the fundamental signal. In the ADRF6603, a Σ - Δ modulator is used to distribute the fractional value randomly, thus significantly reducing the spurious content due to the fractional function.

PROGRAMMING THE ADRF6603

The ADRF6603 is programmed via a 3-pin SPI port. The timing requirements for the SPI port are shown in Figure 2. Eight programmable registers, each with 24 bits, control the operation of the device. The register functions are listed in Table 8.

Table 8. ADRF6603 Register Functions

Register	Function
Register 0	Integer divide control for the PLL
Register 1	Modulus divide control for the PLL
Register 2	Fractional divide control for the PLL
Register 3	Σ - Δ modulator dither control
Register 4	PLL charge pump, PFD, reference path control
Register 5	PLL enable and LO path control
Register 6	VCO control and VCO enable
Register 7	Mixer bias enable and external VCO enable

Note that internal calibration for the PLL must be run when the ADRF6603 is initialized at a given frequency. This calibration is run automatically whenever Register 0, Register 1, or Register 2 is programmed. Because the other registers affect PLL performance, Register 0, Register 1, and Register 2 should always be programmed last and in this order: Register 0, Register 1, Register 2.

To program the frequency of the ADRF6603, the user typically programs only Register 0, Register 1, and Register 2. However, if registers other than these are programmed first, a short delay should be inserted before programming Register 0. This delay ensures that the VCO band calibration has sufficient time to complete before the final band calibration for Register 0 is initiated.

Software is available on the product page of the Analog Devices website (www.analog.com) that allows easy programming from a PC running Windows XP or Vista.

INITIALIZATION SEQUENCE

To ensure proper power-up of the ADRF6603, it is important to reset the PLL circuitry after the VCC supply rail settles to $5\text{ V} \pm 0.25\text{ V}$. Resetting the PLL ensures that the internal bias cells are properly configured, even under poor supply start-up conditions.

To ensure that the PLL is reset after power-up, follow this procedure:

1. Disable the PLL by setting the PLEN bit to 0 (Register 5, Bit DB6).
2. Disable the VCO LDO internal node by setting the LVEN bit to 0 (Register 6, Bit DB18).
3. After a delay of >100 ms, set the PLEN and LVEN bits to 1.

After this procedure, the other registers can be programmed, in order, from Register 7 to Register 3, and then from Register 0 to Register 2, as described in the Programming the ADRF6603 section.

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LO SELECTION LOGIC

The downconverting mixer in the ADRF6603 can be used without the internal PLL by applying an external differential LO to Pin 37 and Pin 38 (LON and LOP). In addition, when using an LO generated by the internal PLL, the LO signal can be accessed directly at these same pins. This function can be used for debugging purposes, or the internally generated LO can be used as the LO for a separate mixer.

The operation of the LO generation and whether LOP and LON are inputs or outputs are determined by the logic levels applied at Pin 16 (PLL_EN) and Pin 36 (LODRV_EN), as well as Bit DB3 (LDRV) and Bit DB6 (PLEN) in Register 5. The combination of externally applied logic and internal bits required for particular LO functions is given in Table 9.

Table 9. LO Selection Logic

Pins ¹		Register 5 Bits ¹		Outputs	
Pin 16 (PLL_EN)	Pin 36 (LODRV_EN)	Bit DB6 (PLEN)	Bit DB3 (LDRV)	Output Buffer	LO
0	X	0	X	Disabled	External
0	X	1	X	Disabled	External
1	X	0	X	Disabled	External
1	0	1	0	Disabled	Internal
1	X	1	1	Enabled	Internal
1	1	1	X	Enabled	Internal

¹X = don't care.

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EVALUATION BOARD

Figure 24 shows the schematic of the RoHS-compliant evaluation board for the ADRF6603. This board has four layers and was designed using Rogers 4350 hybrid material to minimize high frequency losses. FR4 material is also adequate if the design can accept the slightly higher trace loss of this material.

The evaluation board is designed to operate using the internal VCO of the device (the default configuration) or with an external VCO. To use an external VCO, R62 and R12 should be removed. Place 0 Ω resistors in R63 and R11. The input of the external VCO should be connected to the VTUNE SMA connector, and the external VCO output should be connected to the LO IN/OUT SMA connector. In addition to these hardware changes, internal register settings must also be changed to enable operation with an external VCO (see the Register 6—VCO Control and VCO Enable (Default: 0x1E2106) section).

Additional configuration options for the evaluation board are described in Table 10.

EVALUATION BOARD CONTROL SOFTWARE

Software to program the ADRF6603 is available for download from www.analog.com. To install the software, download and extract the zip file. Then run the following installation file:

ADRF6x0x_3p0p0_XP_install.exe

The evaluation board can be connected to the PC using a PC parallel port or a USB port. These options are selectable from the opening menu of the software interface (see Figure 22). The evaluation board is shipped with a 25-pin parallel port cable for connection to the PC parallel port.

To connect the evaluation board to a USB port, a USB adapter board (Part No. EVAL-ADF4XXXZ-USB) must be purchased from www.analog.com. This board connects to the PC using a standard USB cable with USB mini-connector at one end. An additional 25-pin male to 9-pin female adapter is required to mate the ADF4XXXZ-USB board to the 9-pin D-Sub connector on the ADRF6603 evaluation board.

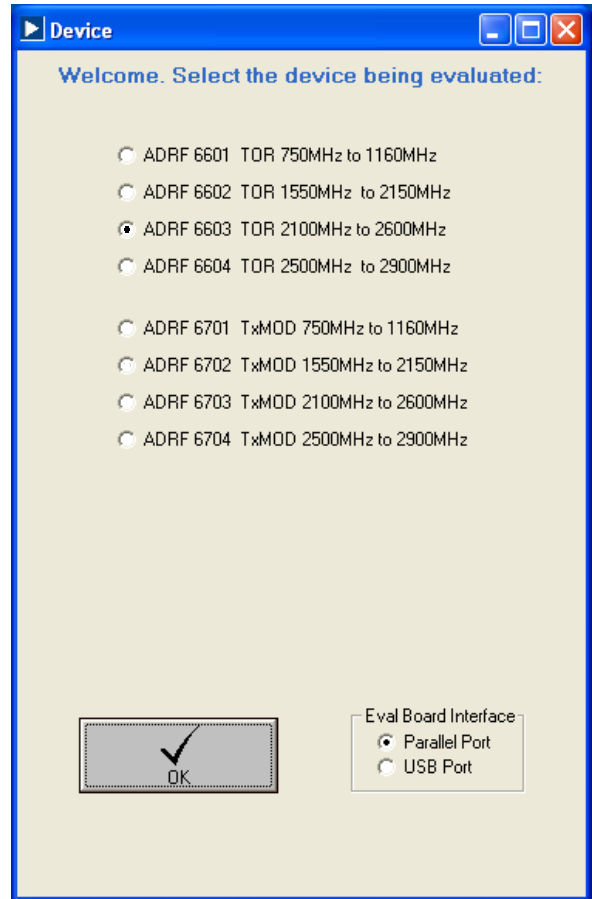


Figure 22. Control Software Opening Menu

Figure 23 shows the main menu of the control software with the default settings displayed.

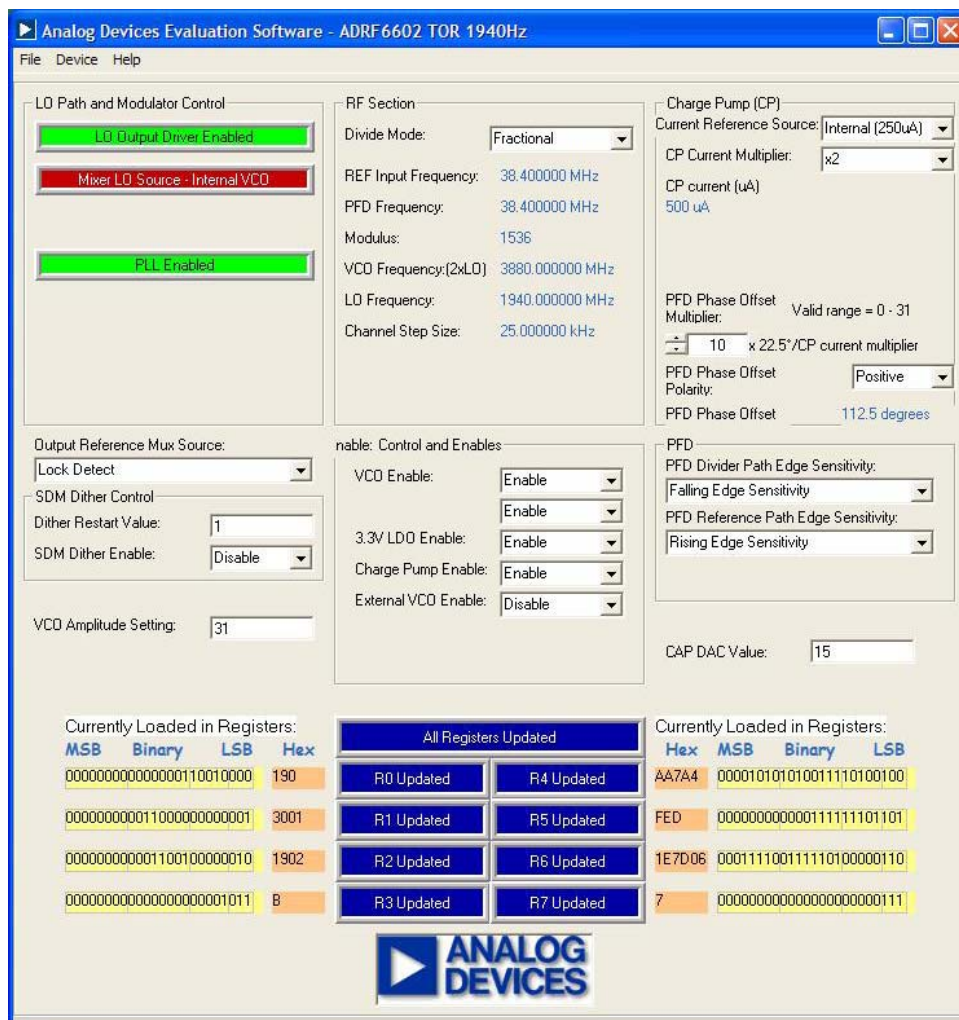


Figure 23. Main Window of the ADRF6603 Evaluation Board Software

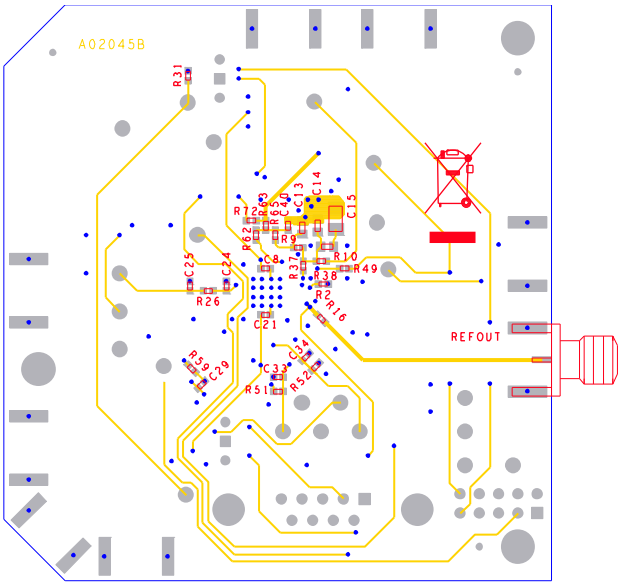


Figure 25. Evaluation Board Layout (Bottom)

08547-013

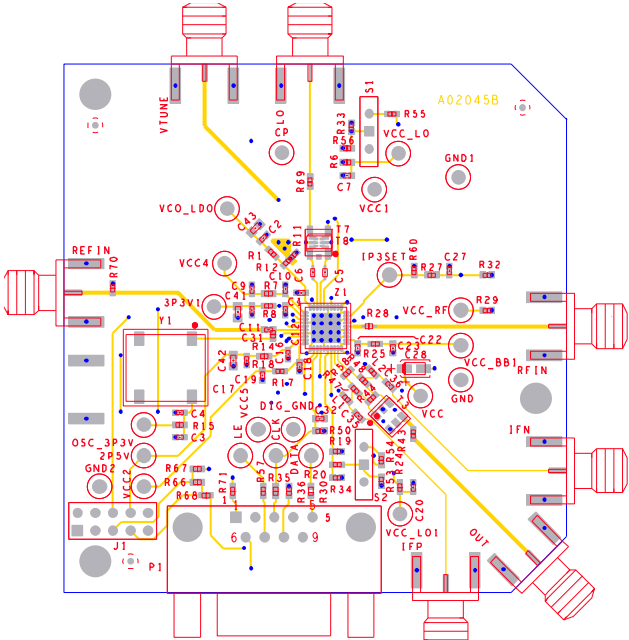


Figure 26. Evaluation Board Layout (Top)

08547-012

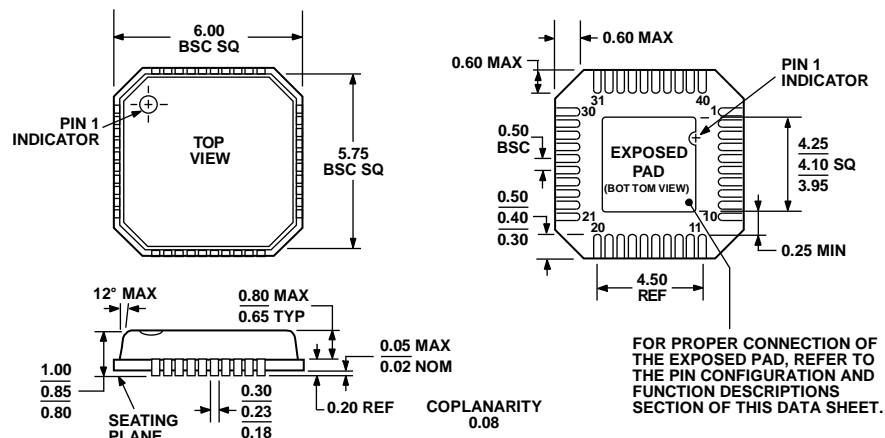
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EVALUATION BOARD CONFIGURATION OPTIONS

Table 10.

Component	Description	Default Condition/ Option Settings
S1, R55, R56, R33	LO select. Switch and resistors to ground the LODRV_EN pin. The LODRV_EN pin setting, in combination with internal register settings, determines whether the LOP and LON pins function as inputs or outputs (see the LO Selection Logic section for more information).	S1 = R55 = open (not installed) R56 = R33 = 0 Ω LODRV_EN = 0 V
LO IN/OUT SMA Connector	LO input/output. An external 1 \times LO or 2 \times LO can be applied to this single-ended input connector.	LO input
REFIN SMA Connector	Reference input. The input reference frequency for the PLL is applied to this connector. Input impedance is 50 Ω .	
REFOUT SMA Connector	Multiplexer output. The REFOUT connector connects directly to the MUXOUT pin. The on-board multiplexer can be programmed to bring out the following signals: REFIN, 2 \times REFIN, REFIN/2, REFIN/4. Temperature sensor output voltage. Lock detect indicator.	Lock detect
CP Test Point	Charge pump test point. The unfiltered charge pump signal can be probed at this test point. Note that the CP pin should not be probed during critical measurements such as phase noise.	
R37, C14, R9, R10, C15, C13, R65, C40	Loop filter. Loop filter components.	
R11, R12	Loop filter return. When the internal VCO is used, the loop filter components should be returned to Pin 40 (DECLVCO) by installing a 0 Ω resistor in R12. When an external VCO is used, the loop filter components can be returned to ground by installing a 0 Ω resistor in R11.	R12 = 0 Ω (0402) R11 = open (0402)
R62, R63, VTUNE SMA Connector	Internal vs. external VCO. When the internal VCO is enabled, the loop filter components are connected directly to the VTUNE pin (Pin 39) by installing a 0 Ω resistor in R62. To use an external VCO, R62 should be left open. A 0 Ω resistor should be installed in R63, and the voltage input of the VCO should be connected to the VTUNE SMA connector. The output of the VCO is brought back into the PLL via the LO IN/OUT SMA connector.	R62 = 0 Ω (0402) R63 = open (0402)
R2	R _{SET} pin. This pin is unused and should be left open.	R2 = open (0402)
RFIN SMA Connector	RF input. The RF input signal should be applied to the RFIN SMA connector. The RF input of the ADRF6603 is ac-coupled, therefore, no bias is necessary.	R3 = R23 = open (0402)
T3	IF output. The differential IF output signals from the ADRF6603 (IFP and IFN) are converted to a single-ended signal by T3.	

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-220-VJJD-2

Figure 27. 40-Lead Lead Frame Chip Scale Package [LFCSP_VQ]
6 mm × 6 mm Body, Very Thin Quad
(CP-40-1)

Dimensions shown in millimeters

072108-A

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
ADRF6603ACPZ-R7	-40°C to +85°C	40-Lead Lead Frame Chip Scale Package [LFCSP_VQ]	CP-40-1
ADRF6603-EVALZ		Evaluation Board	

¹ Z = RoHS Compliant Part.

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NOTES



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